SCRs
1.6 Amp, Planar

2N2322-2N2329
2N2323A-2N2328A

FEATURES
- Available as JAN, JANTXV & JANTXV Types
- 1.6A D.C. Current
- Peak Currents: to 30A
- Voltage Ratings: to 400V
- 20μA Max. Trigger Current ("A" types)
- 0.6V Max. Trigger Voltage ("A" types)

DESCRIPTION
These are premium thyristor switches intended for use in high performance industrial, military and space applications requiring a high degree of reliability assurance. This series is useful in a wide variety of applications including timing and programming circuits, protective and warning circuits, driving relays, driving indicator lamps, encoding and decoding circuits, replacing relays, thyratrons, and magamps, servo motor control, pulse generation, plus many others. The high surge current rating (15A - 1 cycle) makes this series particularly useful for squib firing.

The following JAN, JANTX and JANTXV types are specified under Mil-S-19500/276A and are included in Mil-STD-701 as recommended types for military usage:

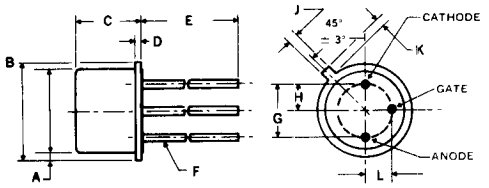
ABSOLUTE MAXIMUM RATINGS

	2N2322	2N2323 JAN2N2323 JANTX2N2323 JANTXV2N2323 2N2323A JAN2N2323A JANTX2N2323A JANTXV2N2323A	2N2324 JAN2N2324 JANTX2N2324 JANTXV2N2324 2N2324A JAN2N2324A JANTX2N2324A JANTXV2N2324A	2N2325	2N2325A	2N2326 JAN2N2326 JANTX2N2326 JANTXV2N2326 2N2326A JAN2N2326A JANTX2N2326A JANTXV2N2326A	2N2327	2N2327A	2N2328 JAN2N2328 JANTX2N2328 JANTXV2N2328 2N2328A JAN2N2328A JANTX2N2328A JANTXV2N2328A	2N2329 JAN2N2329 JANTX2N2329 JANTXV2N2329
Repetitive Peak Off-State Voltage, V_{DRM}	25V	50V	100V	150V		200V	250V		300V	400V
Repetitive Peak Reverse Voltage, V_{RRM}	25V	50V	100V	150V		200V	250V		300V	400V
Non-Repetitive Peak Reverse Voltage, V_{RSM} (< 5ms)	40V	75V	150V	225V		300V	350V		400V	500V

D.C. On-State Current, I_T	
80°C Ambient	300mA
85°C Case	1.6A
One Cycle Surge (Non-Rep.) On-State Current, I_{TSM}	15A
Repetitive Peak On-State Current, I_{TM}	30A
Gate Power Dissipation, P_{GM}	0.1W
Gate Power Dissipation, $P_{GM(AV)}$	0.01W
Peak Gate Current, I_{GM}	100mA
Peak Gate Voltage, Forward and Reverse	6V
Reverse Gate Current, I_{GR}	3mA
Storage Temperature Range	−65°C to +150°C
Operating Temperature Range	−65°C to +125°C

MECHANICAL SPECIFICATIONS

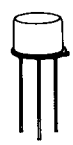
2N2322-2N2329 2N2323A-2N2328A



	ins.	mm.
A	.305-.335	7.75-8.51
B	.335-.370	8.51-9.40
C	.240-.260	6.35-6.60
D	.010-.030	.25-.76
E	.5 MIN.	12.70 MIN.
F	.017 ± .002 .001	432 ± .051 .025
G	.200	5.08
H	.100	2.54
J	.031±.003	.79±.08
K	.029-.045	.74-1.14
L	.100	2.54

TO-5 has 1.5" (38.10mm) lead length

TO-39



JAN types available in TO-5 package upon request.

UNITRODE

ELECTRICAL SPECIFICATIONS

Test	Symbol	Min.	Typical	Max.	Units	Test Conditions
Visual and Mechanical						MIL-STD-750, Method 2071
25°C						
Off-State Current	I_{DRM}	—	0.1	10	μA	V_{DRM} = Rating, R_{GK} = 1K (2K for "A" Types)
Reverse Current	I_{RRM}	—	0.1	10	μA	V_{RRM} = Rating, R_{GK} = 1K (2K for "A" Types)
Gate Trigger Current	I_{GT}					
"A" Types		—	2	20	μA	V_D = 6V, R_L = 100Ω
non-"A" Types		—	50	200	μA	V_D = 6V, R_L = 100Ω
Gate Trigger Voltage	V_{GT}					
"A" Types		0.35	0.52	0.60	V	V_D = 6V, R_{GK} = 2K, R_L = 100Ω
non-"A" Types		0.35	0.55	0.80	V	V_D = 6V, R_{GK} = 1K, R_L = 100Ω
On-State Voltage	V_{TM}	—	2.0	2.2	V	I_{TM} = 4A (pulse test)
Holding Current	I_H	—	0.3	2.0	mA	V_D = 6V, R_{GK} = 1K (2K for "A" Types)
Reverse Gate Current	I_{GR}	—	1	200*	μA	V_{GR} = 6V
Delay Time	t_d	—	0.6	—	μs	I_G = 10mA, I_T = 1A, V_D = 30V
Rise Time	t_r	—	0.4	—	μs	I_G = 10mA, I_T = 1A, V_D = 30V
Circuit Commutated Turn-Off Time	t_q	—	20	—	μs	I_T = 1A, I_R = 1A, R_{GK} = 1K
125°C						
Off-State Current	I_{DRM}	—	1	100	μA	V_{DRM} = Rating, R_{GK} = 1K (2K for "A" Types)
Reverse Current	I_{RRM}	—	1	100	μA	V_{RRM} = Rating, R_{GK} = 1K (2K for "A" Types)
Gate Trigger Voltage	V_{GT}	0.1	0.3	—	V	V_D = Rated V_D, R_{GK} = 1K (2K for "A" Types)
Holding Current	I_H					
"A" Types		0.1†	—	—	mA	V_D = 6V, R_{GK} = 2K
non-"A" Types		0.15†	—	—	mA	V_D = 6V, R_{GK} = 1K
Off-State Voltage — Critical Rate of Rise	dv/dt					
"A" Types		0.7*			V/μs	V_D = Rating, R_{GK} = 2K
non-"A" Types		1.8*			V/μs	V_D = Rating, R_{GK} = 1K
−65°C						
Off-State Current	I_{DRM}	—	.05	5.0*	μA	V_{DRM} = Rating, R_{GK} = 1K (2K for "A" Types)
Reverse Current	I_{RRM}	—	.05	5.0*	μA	V_{RRM} = Rating, R_{GK} = 1K (2K for "A" Types)
Gate Trigger Current	I_{GT}					
"A" Types		—	50	75	μA	V_D = 6V, R_L = 100Ω
non-"A" Types		—	100	350	μA	V_D = 6V, R_L = 100Ω
Gate Trigger Voltage	V_{GT}					
"A" Types		—	0.7	0.8*	V	V_D = 6V, R_{GK} = 2K, R_L = 100Ω
				0.9†	V	V_D = 6V, R_{GK} = 2K, R_L = 100Ω
non-"A" Types		—	0.75	1.0	V	V_D = 6V, R_{GK} = 1K, R_L = 100Ω
Holding Current	I_H	—	—	3.0†	mA	V_D = 6V, R_{GK} = 1K (2K for "A" Types)

* JAN and JANTX Types only.
† Industrial Types only.

X

JAN and JANTX Acceptance Tests

100% Screening TX-Types

High Temperature Storage
Temperature Cycling
Constant Acceleration
Fine & Gross Hermetic Seal
Electrical Test
Burn-in
Electrical Test

Group B Tests

Subgroup 1 — Reverse Gate Current
Surge Current
Non-Repetitive Reverse Voltage

Subgroup 2 — Low Temp. Reverse Blocking Current
Low Temp. Forward Blocking Current
Low Temp. Gate Trigger Voltage
Low Temp. Gate Trigger Current

Subgroup 3 — Temperature Cycling
Thermal Shock
Moisture Resistance
Solderability

Subgroup 4 — Blocking Life Test

Group C Tests

Subgroup 1 — Physical Dimensions

Subgroup 2 — Shock
Constant Acceleration
Vibration, Variable Frequency

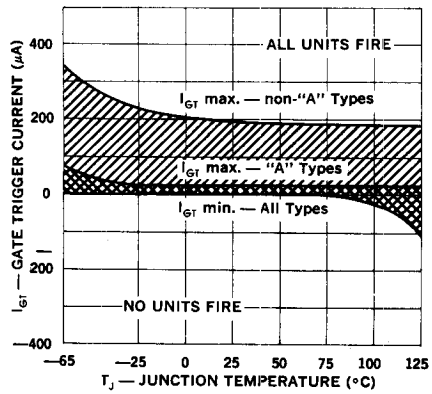
Subgroup 3 — Barometric Pressure, Reduced

Subgroup 4 — Salt Atmosphere

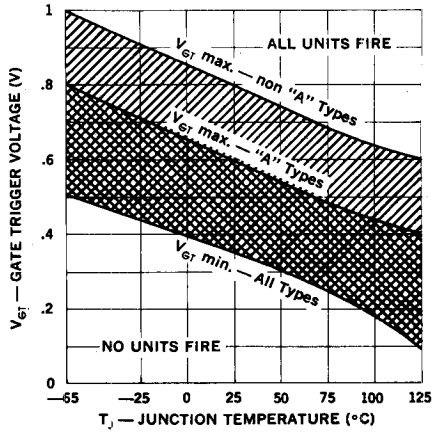
Subgroup 5 — Terminal Strength

Subgroup 6 — Intermittent Operating Life Test

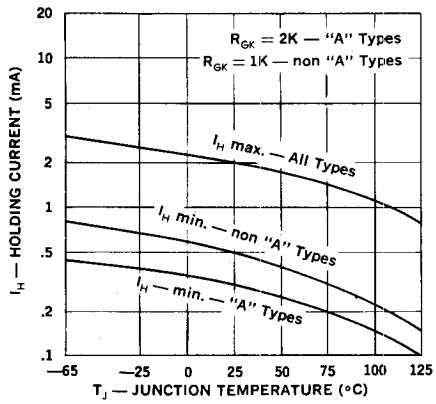
Gate Trigger Current



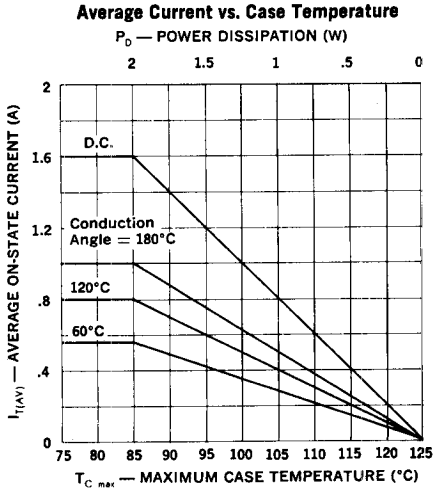
Gate Trigger Voltage



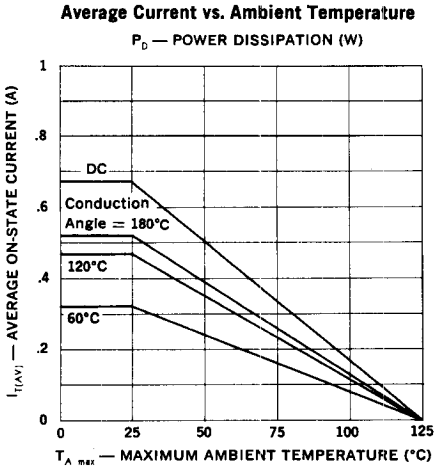
Holding Current



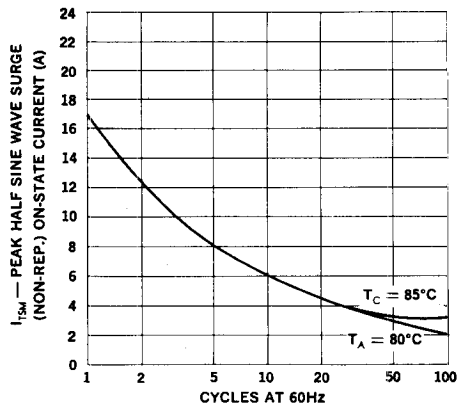
Average Current vs. Case Temperature



Average Current vs. Ambient Temperature



Surge Current



UNITRODE CORPORATION • 5 FORBES ROAD
LEXINGTON, MA 02173 • TEL. (617) 861-6540
TWX (710) 326-6509 • TELEX 95-1064

PRINTED IN U.S.A.